

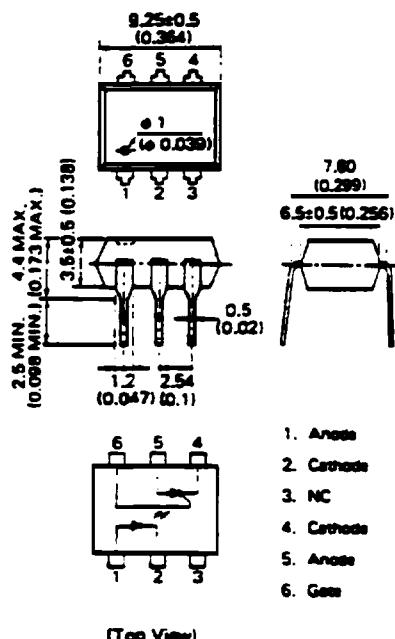
PHOTO SCR COUPLERS
PS3001 (1), PS3002 (1)

PHOTO SCR COUPLER

DESCRIPTION

The PS3001 and PS3002 are optically coupled isolators containing GaAs infrared emitting diode and a PNPN silicon photo SCR.

PACKAGE DIMENSIONS
in millimeters (inches)



(Top View)

FEATURES

- High Voltage Isolation 2500 VDC MIN.
- Low Turn on Current 12 mA MAX.
- Plastic dual-in-line package
- High Speed Switching
- Economical, Compact.

APPLICATIONS

- Interface circuit for various instrumentations, control equipments
- Replaceable from a reed relay

ABSOLUTE MAXIMUM RATINGS (Ta=25 °C)

Diode

Reverse Voltage	VR	6 V
Forward Current (DC)	IF	80 mA
Peak Forward Current	IFP	3 A
Power Dissipation	PD	100 mW

SCR

Peak Off and Reverse Voltage	VDRM, VRMM	PS3001 200 V
		PS3002 400 V
Direct On-State Current	IT	300 mA
Peak pulse current *1	ITP	3 A
Peak surge on Current	ITSM	3 A
Power Dissipation	PSCR	350 mW
Isolation Voltage *2	BV	2500 VAC
Storage Temperature	Tstg	-55 to +125 °C
Operation Temperature	Topt	-55 to +100 °C
Lead Soldering Time (at 260 °C)		10 s.

ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$)

CHARACTERISTIC		SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Diode	Forward Voltage	V_F		1.1	1.4	V	$I_F=20 \text{ mA}$
	Reverse Current	I_R		10	μA		$V_R=6 \text{ V}$
	Junction Capacitance	C_J	50			pF	$V=0, f=1.0 \text{ MHz}$
	Peak Off-State Current	I_{DRM}		10	μA		$V_{DRM}=\text{Rated}$ $R_{GK}=27 \text{ k}\Omega$ $T_a=100^\circ\text{C}$
	Reverse Current	I_{RRM}		10	μA		
	On State Voltage	V_{TM}		1.3		V	$I_T=300 \text{ mA}$
Photo SCR Coupled	Holding Current	I_H		0.2	1	mA	$R_{GK}=27 \text{ k}\Omega, V_D=24 \text{ V}$
	Rate of rise of forward blocking Voltage	dV/dt	0.5	1.0		V/ μs	$V_{DRM}=\text{Rated}$ $R_{GK}=27 \text{ k}\Omega, T_a=100^\circ\text{C}$
	Turn on Current *3	I_{FT}		5	12	mA	$V_D=6 \text{ V}, R_{GK}=27 \text{ k}\Omega$
	Isolation breakdown Voltage	$V_{1.2}$	2500			V _{DC}	DC/1 minute
	Isolation Resistance	$R_{1.2}$	10^{11}			Ω	$V_{in-out}=1.0 \text{ kV}$
	Isolation Capacitance	$C_{1.2}$		0.8		pF	$V=0, f=1.0 \text{ MHz}$
Turn on Time *4		t_{on}		10		μs	$I_{FT}=50 \text{ mA}, V_D=6 \text{ V}$ $R_{GK}=27 \text{ k}\Omega, R_L=100 \Omega$

*1 pulse width = 100 μs

Repetitive Frequency = 100 Hz

*2 Measuring Condition

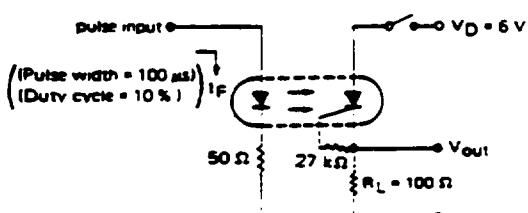
DC voltage for 1 minute at $T_a = 25^\circ\text{C}$; RH = 60 %
 Between input (pin No. 1, 2 and No. 3 Common)
 and output (pin No. 4, 5 and No. 6 Common)

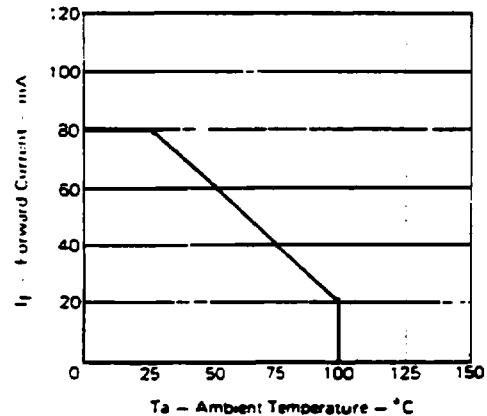
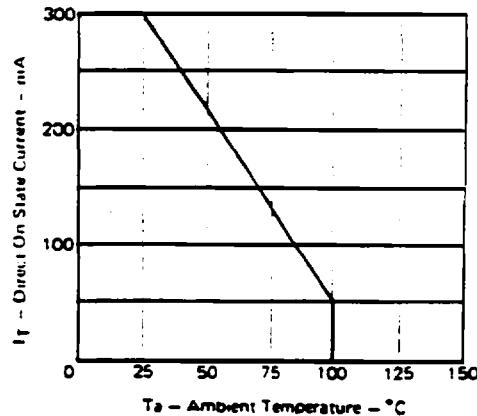
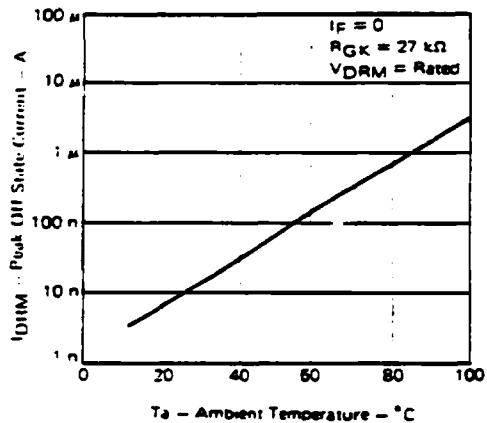
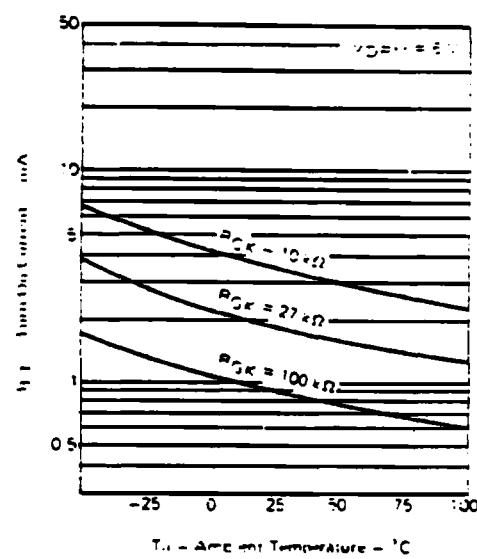
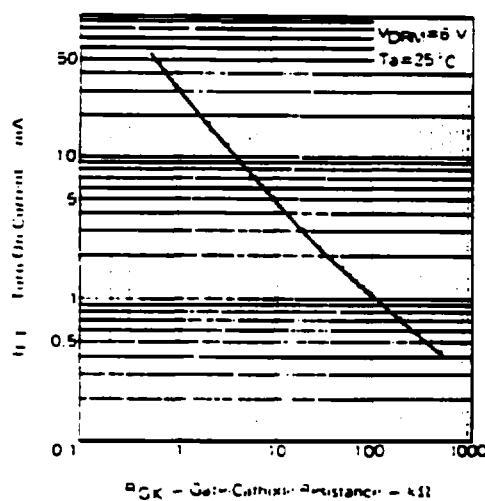
*3 I_{FT} rank

KX : to 12 mA

LX : to 7 mA

*4 Turn on Time Test Circuit



TYPICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)FORWARD CURRENT vs.
AMBIENT TEMPERATUREDIRECT ON-STATE CURRENT vs.
AMBIENT TEMPERATUREPEAK OFF-STATE CURRENT vs.
AMBIENT TEMPERATURETURN ON CURRENT vs.
AMBIENT TEMPERATURETURN ON CURRENT vs.
GATE-CATHODE RESISTANCE $\square R_{GK} = \text{Gate-Cathode Resistance} = \text{k}\Omega$